## NSN 5962-01-287-0075

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View Online at https://aerobasegroup.com/nsn/5962-01-287-0075 **Body Length:** 0.458 inches **Body Width:** 0.458 inches **Body Height:** 0.114 inches **Maximum Power Dissipation Rating:** 413.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and high speed and programmed and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Current Rating Per Characteristic:** 120.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 35.00 nanoseconds delay **Memory Device Type:** Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 leadless Shelf Life: N/a **Unit Of Measure:** 

Demilitarization:

Yes - demil/mli

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